L	Hits	Search Text	DB	Time stamp
Number	234	(349/114).CCLS.	USPAT;	2004/08/04
15	234	(349/114).0015.	US-PGPUB;	13:48
			EPO; JPO;	13.40
			DERWENT	
16	1492	(349/42).CCLS.	USPAT;	2004/08/04
10	1432	(343/42):0010:	US-PGPUB;	13:48
			EPO; JPO;	20010
			DERWENT	
17	1042	(349/138).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
			DERWENT	
18	1006	(349/43).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
19	194	(349/44).CCLS.	DERWENT USPAT;	2004/08/04
19	194	(349/44).CCES.	US-PGPUB;	13:49
}			EPO; JPO;	*3.35
			DERWENT	
20	1553	(257/59).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
			DERWENT	
21	1442	(257/72).CCLS.	USPAT;	2004/08/04
			US-PGPUB;	13:49
			EPO; JPO;	
22	1006	(240/42) CCTC	DERWENT	2004/09/04
22	1006	(349/43).CCLS.	USPAT; US-PGPUB;	2004/08/04 13:49
			EPO; JPO;	13.49
			DERWENT	
23	461	((257/59).CCLS.) and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	13:52
		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
24	396		USPAT;	2004/08/04
		element TFT)) and (insulat\$3 passivat\$3)	US-PGPUB;	13:52
		same organic and pixel	EPO; JPO;	
25	335	 (liquid adj crystal adj display LCD) and	DERWENT USPAT;	2004/08/04
20	333	reflective and (insulating passivation)	US-PGPUB;	13:52
		adj2 layer same organic and (switching	EPO; JPO;	13.32
		adj2 element TFT)	DERWENT	
27	280	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	13:54
		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
120	1.00	and reflector	110000	2004/00/04
28	168	(349/46).CCLS.	USPAT;	2004/08/04
			US-PGPUB; EPO; JPO;	13:54
			DERWENT	
26	379	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	14:06
		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
		and reflective near2 (electrode film		
1		layer)		
29	426	,	USPAT;	2004/08/04
		acrylic) same (insulat\$3 passivat\$3)	US-PGPUB;	14:39
1			EPO; JPO;	
			DERWENT	

30	409	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	14:12
1		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
1		and (transflective transflector		
		transreflective reflective near2		
		(electrode film layer))		
31	147	349/\$.ccls. and (TFT transistor) and	USPAT;	2004/08/04
		(organic BCB PCB polyimide acetyl acrylic	US-PGPUB;	14:12
		adj2 resin) same (passivation passivating	EPO; JPO;	
		insulation insulating) near2 (film layer)	DERWENT	
		and (transflective transflector		
		transreflective)		